

## Features

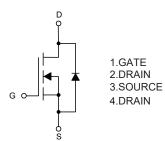
- High Current Rating
- Lower R<sub>DS(ON)</sub>
- Lower Capacitance
- Lower Total Gate Charge
- Tighter V<sub>SD</sub> Specifications
- Avalanche Energy Specified
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free Available Upon Request By Adding Suffix "-HF"
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

### **Maximum Ratings**

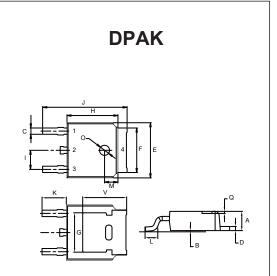
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 100°C/W Junction to Ambient

Parameter	Symbol	Rating	Unit
Drain -Source Voltage	$V_{\text{DS}}$	600	V
Gate -Source Volltage	V <sub>GS</sub>	±30	V
Drain Current-Continuous	I <sub>D</sub>	4.0	А
Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	4.0	А
Power Dissipation	P <sub>D</sub>	1.25	W
Single Pulsed Avalanche Energy <sup>(Note1)</sup>	E <sub>AS</sub>	260	mJ

## **Internal Structure**



# N-CHANNEL MOSFET



DIM INCHES			MM		NOTE
2	MIN	MAX	MIN	MAX	
А	0.087	0.094	2.20	2.40	
В	0.000	0.000 0.005		0.13	
C 0.026 0.		0.034	0.66	0.86	
D	D 0.018 0.023		0.46	0.58	
Е	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		0 4.83		TYP.
Н	0.236	0.244	6.00	6.20	
Ι	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
Κ	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
М	0.063		1.60		TYP.
0	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.	35	TYP.



## **ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)**

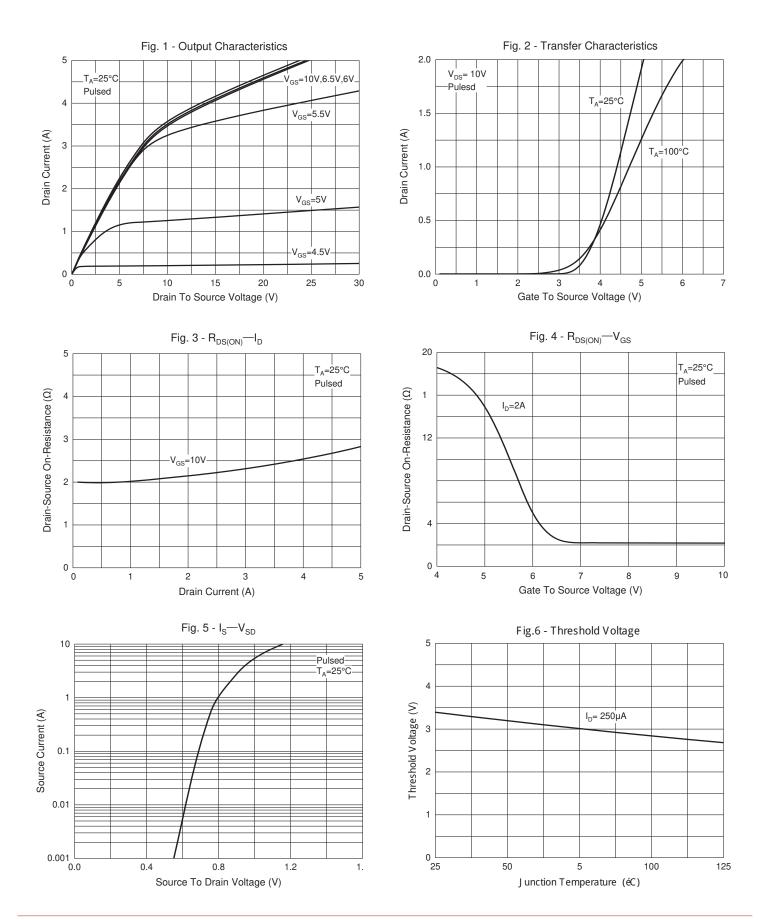
Parameter	Symbol	Test conditions	Min	Тур	Max	Unit
Static Characteristics	I				I	
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250µA	600			V
Gate-Threshold Voltage <sup>(Note2)</sup>	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2.0		4.0	V
Gate-Body Leakage Current <sup>(Note2)</sup>	I <sub>GSS</sub>	V <sub>GS</sub> =± 30V, V <sub>DS</sub> =0V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V			25	μA
Drain-Source On-Resistance <sup>(Note2)</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =2A		2	3	Ω
Drain- Source Diode Forward Voltage <sup>(Note2)</sup>	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =4A			1.5	V
Forward Transconductance <sup>(Note2)</sup>	9 <sub>fs</sub>	V <sub>DS</sub> =50V, I <sub>D</sub> =2A	2.5			S
Dynamic Characteristics						
Input Capacitance <sup>(Note3)</sup>	C <sub>iss</sub>			540	760	pF
Output Capacitance <sup>(Note3)</sup>	C <sub>oss</sub>	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, f=1MHz		125	180	
Reverse Transfer Capacitance <sup>(Note3)</sup>	C <sub>rss</sub>			8	20	
Switching Characteristics						
Total Gate Charge	Qg			5	10	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =480V, $V_{GS}$ =10V, $I_{D}$ =4A		2.7		Nc
Gate-Drain Charge	$Q_gd$			2		
Turn-on Delay Time <sup>(Note3)</sup>	t <sub>d(on)</sub>			12	20	
Turn-on Rise Time <sup>(Note3)</sup>	t <sub>r</sub>	V <sub>DD</sub> =300V,V <sub>GS</sub> =10V,R <sub>G</sub> =9.1Ω,		7	10	
Turn-off Delay Time <sup>(Note3)</sup>	t <sub>d(off)</sub>	I <sub>D</sub> =4A		19	40	ns
Turn-off Fall Time <sup>(Note3)</sup>	t <sub>f</sub>			10	20	

Note: 1. L=30mH,  $I_L$ =4A, $V_{DD}$ =100V, $V_{GS}$ =10V, $R_G$ =25 $\Omega$ ,Starting T<sub>J</sub>=25°C

2. Pulse Test : Pulse Width  ${\leqslant}300\mu s,$  Duty Cycle  ${\leqslant}2\%$ 

3. These Parameters Have No Way to Verify

# **Curve Characteristics**





## **Ordering Information**

	Device	Packing		
Part Number-TP		Tape&Reel:2.5Kpcs/Reel		

Note : Adding "-HF" Suffix For Halogen Free, eg. Part Number-TP-HF

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